

Dual transil array for ESD protection

General Description

The LESDA6V1LLT1G is a dual monolithic voltage suppressor designed to protect components which are connected to data and transmission lines against ESD. It clamps the voltage just above the logic level supply for positive transients, and to a diode drop below ground for negative transients. It can also work as bidirectionnal suppressor by connecting only pin1 and 2.

Applications

- Computers
- Printers
- Communication systems

It is particulary recommended for the RS232 I/O port protection where the line interface withstands only with 2kV ESD surges.

Features

- 2 Unidirectional Transil functions
- Low leakage current: $I_R \max < 20 \mu A$ at VBR
- 3 00W peak pulse power($8/20 \mu s$)
- High ESD protection level: up to 25 kV

Benefits

- High ESD protection level
- up to 25 kV. High integration.
- Suitable for high density boards.

Complies with the following standards

IEC61000-4-2 Level 4

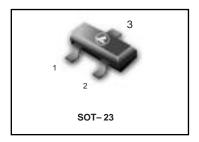
MIL STD 883c - Method 3015-6 Class 3

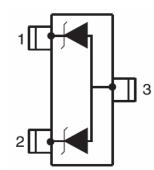
(Human Body Model)

Absolute Ratings ($T_{amb}=25^{\circ}C$)

Symbol	Parameter	Value	Units	
P_{PP}	Peak Pulse Power (t₀ = 8/20µs)	300	W	
T_L	Maximum lead temperature for soldering during 10s	260	Ŝ	
T _{stg}	Storage Temperature Range	-55 to +150	°C	
T _{op}	Operating Temperature Range	-40 to +125	°C	
T _j	Maximum junction temperature	150	°C	
V _{PP}	Electrostatic discharge			
	MIL STD 883C -Method 3015-6	25	kv	
	IEC61000-4-2 air discharge	16		
	IEC61000-4-2 contact discharge	9		

LESDA6V1LLT1G





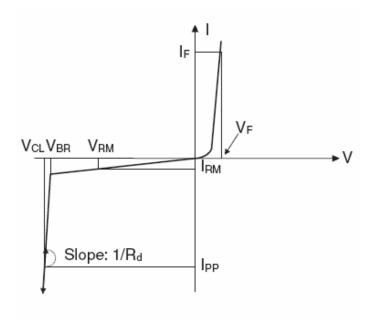
Ordering Information

Device	Marking	Shipping		
LESDA6V1LLT1G	E61	3000/Tape&Reel		
LESDA6V1LLT3G	E61	10000/Tape&Reel		



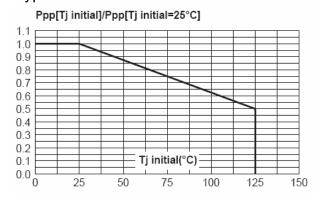
Electrical Parameter

Symbol	Parameter
V_{RM}	Stand-off voltage
V_{BR}	Breakdown voltage
V _{CL}	Clamping voltage
I _{RM}	Leakage current
I _{PP}	Peak pulse current
αΤ	Voltage temperature coefficient
V _F	Forward voltage drop
С	Capacitance
R _d	Dynamic resistance



Part Numbers	V_{BR}				V _F		R _d	α T	С
	Min.	Max.	V_{RM}	I _{RM}	Max.	l _F	Typ. ⁽¹⁾	Max. ⁽²⁾	Typ. 0v bias
	٧	٧	V	μД	٧	mA	mΩ	10 ⁻⁴ /°C	pF
LESDA6V1LLT1G	6.1	7.2	5.25	20	1.25	200	350	6	140

Typical Characteristics



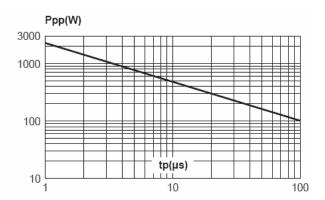
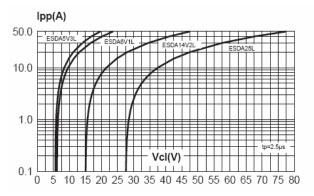


Fig1.Peak power dissipation versus Initial junction temperature

Fig2. Peak pulse power versus exponential pulse duration(T_j initial=25°C)

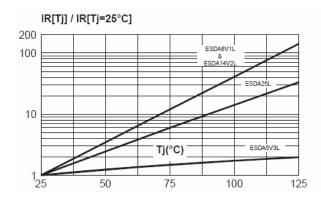


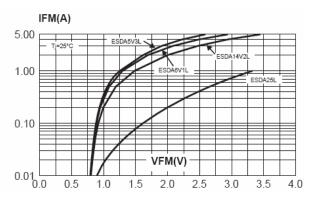


C(pF) 200 F=1MHz 100 50 ESDA14V2L 20 ESDA25L VR(V) 10 5 10 20 50

Fig3. Clamping voltage versus peak pulse current(T_i initial=25°C, Waveform, t_p =2.5 μ s) rectangular

Fig4. Capacitance versus reverse Applied voltage





Versus junction temperature

Fig5.Relative variation of leakage current Fig6. Peak forward voltage drop versus peak forward current

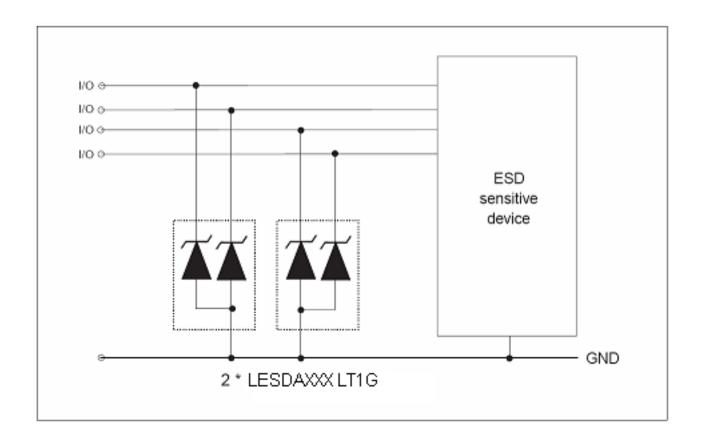
Application Note

Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS arrays offer the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal line to ground. As the transient rises above the operating voltage of the device, the TVS array becomes a low impedance path diverting the transient current to ground. The ESDAxxL array is the ideal board evel protection of ESD sensitive semiconductor components.

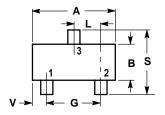
The tiny SOT23 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening againt ESD.

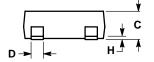


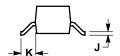




SOT-23



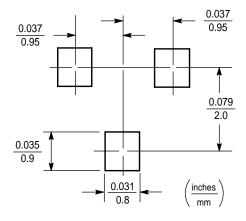




NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
- 2. CONTROLLING DIMENSION: INCH.

DIM	II	ICHES	MILLIMETERS		
	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
Н	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
K	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
V	0.0177	0.0236	0.45	0.60	



单击下面可查看定价,库存,交付和生命周期等信息

>>LRC(乐山无线电)